



**ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
INPUT	Forward Voltage	$V_F$	$I_F = 10\text{mA}$	1.0	1.15	1.3	V	
	Reverse Current	$I_R$	$V_R = 5\text{V}$	—	—	10	$\mu\text{A}$	
	Capacitance	$C_T$	$V_T = 0\text{V}$ , $f = 1\text{MHz}$	—	20	—	pF	
OUTPUT	Peak Off-State Current	$I_{DRM}$	$V_{DRM} = \text{Rated}$	—	—	10	$\mu\text{A}$	
	Peak On-State Voltage	$V_{TM}$	$I_{TM} = 4.5\text{A}$	—	—	1.5	V	
	Holding Current	$I_H$	$V_D = 6\text{V}$ , Beginning Current = 1A	—	—	25	mA	
	Critical Rate of Rise of Off-State Voltage	$dv/dt$	$V_{DRM} = \text{Rated}$	—	2000	—	$\text{V} / \mu\text{s}$	
	Critical Rate of Rise of Commutating Voltage	$(dv/dt)_c$	$V_D = 400\text{V}$ , $-di/dt = 30\text{A/ms}$	—	30	—	$\text{V} / \mu\text{s}$	
	Thermal Resistance	Junction to Lead	$R_{th(j-\ell)}$	AC	—	—	20	$^{\circ}\text{C/W}$
		Junction to Ambient	$R_{th(j-a)}$	AC	—	—	85	$^{\circ}\text{C/W}$

**COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	$I_{FT}$	$V_D = 6\text{V}$ , $R_L = 20\Omega$	—	—	10	mA
Capacitance (Input to output)	$C_S$	$V_S = 0\text{V}$ , $f = 1\text{MHz}$	—	0.5	—	pF
Isolation Resistance	$R_S$	$V = 500\text{V}$ , $RH \leq 60\%$	$10^9$	—	—	$\Omega$
Turn-off Time	$t_{off}$	OUTPUT : Sine Waveform	—	—	3 / 4	cycle

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## &lt;REMARK&gt;

## PHASE CONTROL APPLICATION

In case of using in phase control application.  $\Delta t$  must be at least 1ms ( $\Delta t$  : The time starting from the end of INPUT SIGNAL "point a" to the point at which load current become ZERO "point b"). And, Load current " $I_T$ " at "point a" must be at least double the maximum Holding Current ( $I_H$ ) specification in each operating temperature.





